## Chemical nature of the pairing of holes in high-temperature superconductors

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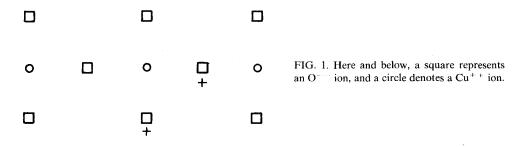
(Submitted 27 December 1988)

Pis'ma Zh. Eksp. Teor. Fiz. 49, No. 2, 119–121 (25 January 1989)

Some crude arguments which point toward a purely electronic (chemical) mechanism for the pairing of p-holes at oxygen are offered. These ideas stem from the fact that reactions of the type  $(O^- \text{ radical}) \rightarrow (\text{the peroxide } O_2^{--}) \rightarrow (O^{--} \text{ ion } + O_2 \text{ molecule})$  occur in the gas phase.

Experimental results acquired over the past year could possibly be interpreted as evidence for an oxygen-hole nature of high-temperature superconductivity, according to which the current carriers would be p-holes localized primarily at O<sup>--</sup> ions. A mechanism of this sort could obviously operate not only in substances having CuO<sub>2</sub> layers but also in compounds which have no copper at all. The magnetic properties would be secondary; in any case, they would not necessarily play a leading role in the pairing process.

This idea was recently formulated clearly by Hirsh. <sup>1,2</sup> Hirsh also proposed a universal mechanism for the local pairing of *p*-holes, by virtue of the polarization produced by the pair at one (!) O<sup>--</sup> ion. In other words, the pairing results from the exchange of a local dipole (primarily electronic) mode. The corresponding equations, written in the Migdal approximation,<sup>3</sup> are the same as the results of a recent study by Éliashberg,<sup>4</sup> who took into account the exchange of several local Einstein (oxygen) modes. I would like to offer some crude, qualitative arguments in support of Hirsh. These arguments are based on the properties of oxygen and its atomic and molecular ions in the gas phase. Clearly, a mechanism of this sort is of a purely electronic (chemical nature).



We know quite well that the  $O^-$  radical is chemically unstable in a gas, forming the peroxide molecule  $O_2$ :

$$20^{-} \rightarrow 0_{2}^{-}. \tag{1}$$

Moreover, the peroxide is also unstable at a sufficient gas density:

$$20_2^- \rightarrow 20^- + 0_2 \uparrow. \tag{2}$$

What do reactions (1) and (2) imply for a solid oxide? (For definiteness, I will speak in terms of CuO<sub>2</sub> layers.) The O<sup>--</sup> ion is a normal (ionic) state of oxygen in CuO<sub>2</sub> layers in La<sub>2</sub>CuO<sub>4</sub> and YBa<sub>2</sub>Cu<sub>3</sub>O<sub>6</sub>. The localization of *p*-holes at O<sup>--</sup> which occurs upon the doping of La<sub>2</sub>CuO<sub>4</sub> or in the transition from YBa<sub>2</sub>Cu<sub>3</sub>O<sub>6</sub> to YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7</sub> converts the O<sup>--</sup> into the unstable (metallic) radical O<sup>-</sup>. Reaction (1) is a "Cooper pairing" of holes. The size of the O<sub>2</sub> "Cooper pair" (in other words, the size of the mobile chemical bond) is accordingly small (Fig. 1), and its energy must of course be estimated at the scale of oxidation-reduction reactions. A factor which lowers the transition temperature is the difference between the size of the peroxide molecule in a gas and that in a solid oxide (a lattice gas).

Reaction (2), which goes at a high hole density, restores the "superconductor"  $O_2$  to an insulating state, in this instance constituting a lattice of  $O_2$  molecules against the background of the original  $O^{--}$  ions. In "truly neutral"  $O_2$ , all four holes could be said to be on two valence bonds (Fig. 2). A likely alternative in the solid phase might be bound states of four *p*-holes (of the types in Figs. 3a and 3b) linking  $O_2$  and two  $O^{--}$  ions. Relatively immobile configurations (Figs. 2 and 3) will undoubtedly tend to form a charge density wave.

Phase diagrams including ionic, metallic (superconducting), and charge-density-wave phases have been analyzed from the chemical standpoint by Sleight,<sup>5</sup> among others. Sleight assumed, however, that the key chemical properties are those of the cations, so that the roles of the insulator  $O^{--}$ ,  $O_2$ ; the metal  $O^-$ ,  $O_2$ ; and reaction

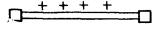


FIG. 2.

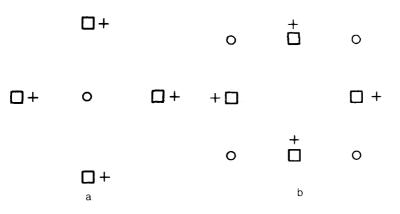


FIG. 3.

(2) in his description were played by, for example, the metal Bi<sup>4+</sup>; the insulator Bi<sup>3+</sup>, Bi<sup>5+</sup>; and the disproportionation reaction

$$2Bi^{4+} \rightarrow Bi^{3+} + Bi^{5+}$$
 (3)

That mobile oxygen p-holes of  $O^-$  and  $O_2$  would survive in a significant density in solid oxides in the face of reaction (2) is of course somewhat miraculous. It is evidence of a structural instability, as follows from the well-known argument of Bengt Mathias. However, the calculations in the papers by Hirsh which we have cited inspire faith in this miracle.

Translated by Dave Parsons

<sup>&</sup>lt;sup>1</sup>J. E. Hirsh, "Finite systems studies and the mechanisms of high  $T_c$ ," in: Proceedings of the NEC Symposium on Mechanisms of High Temperature Superconductivity, Springer-Verlag, in press, 1988.

<sup>&</sup>lt;sup>2</sup>J. E. Hirsh, "Hole superconductivity," UCSD preprint, October, 1988.

<sup>&</sup>lt;sup>3</sup>A. B. Migdal, Zh. Eksp. Teor. Fiz. **34**, 1438 (1958) [Sov. Phys. JETP **7**, 996 (1985)].

<sup>&</sup>lt;sup>4</sup>G. M. Éliashberg, Pis'ma Zh. Eksp. Teor. Fiz. 48, 275 (1988) [JETP Lett. 48, 305 (1988)].

<sup>&</sup>lt;sup>5</sup>A. W. Sleight, "Oxide superconductors: structure-property relationships and mechanisms for high  $T_c$ ," in: Superconductivity: Synthesis, Properties and Processing, (ed. W. Hatfield), Marcel Dekker Inc., 1988.